RICHTEK®

9W Stereo Class-D Audio Power Amplifier

General Description

The RT9108NL is a high efficiency Class D stereo audio amplifier for driving Bridge Tied Load (BTL) speakers. The RT9108NL can drive stereo speakers with load as low as 4Ω . Its high efficiency eliminates the need for an extra heat sink when playing music. The gain of the amplifier can be controlled by two gain select pins. The outputs are fully protected against shorts to GND, PV_{CC}, and output to output with an auto recovery feature and monitored output.

Ordering Information

RT9108NL

-Package Type

CP : TSSOP-28 (Exposed Pad-Option 3)

-Lead Plating System Z : ECO (Ecological Element with Halogen Free and Pb free)

Note :

Richtek products are :

- RoHS compliant and compatible with the current requirements of IPC/JEDEC J-STD-020.
- Suitable for use in SnPb or Pb-free soldering processes.

Marking Information

RT9108NL ZCPYMDNN RT9108NLZCP : Product Number YMDNN : Date Code

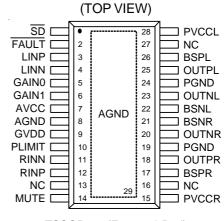
Features

- 8V to 16V Input Supply Range
- 9W/CH into an 8 Ω Load from 12V Supply at 10% THD+N
- 88% Efficiency Eliminates Need for Heat Sinks
- Four Selectable or Fixed Gain Settings
- Robust Pin-to-Pin Short Circuit Protection
- Thermal Protection with Auto Recovery Option
- Surface Mount TSSOP-28 (Exposed Pad) Package
- RoHS Compliant and Halogen Free

Applications

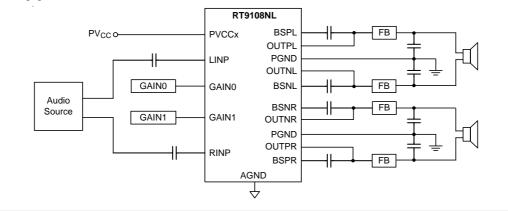
- LCD-TV
- Monitors
- DVD Players

Pin Configurations



TSSOP-28 (Exposed Pad)

Simplified Application Circuit





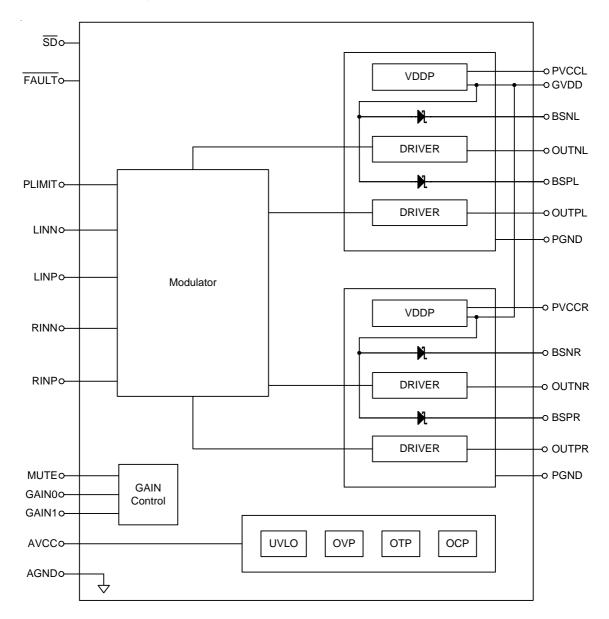
Functional Pin Description

| Pin No. | Pin Name | Pin Function | | |
|--|----------|---|--|--|
| 1 | SD | Shutdown Logic Input for Audio Amp (High = outputs enabled). TTL logic levels with compliance to AVCC. | | |
| 2 FAULT | | Open Drain Output used to Display Short Circuit Fault Status. Voltage compliant to AVCC. Short circuit faults can be set to auto recovery by connecting FAULT pin to \overline{SD} pin. | | |
| 3 | LINP | Positive Audio Input for Left Channel. Biased at 2V. | | |
| 4 | LINN | Negative Audio Input for Left Channel. Biased at 2V. | | |
| 5 | GAIN0 | Gain Select Least Significant Bit. | | |
| 6 | GAIN1 | Gain Select Most Significant Bit. | | |
| 7 | AVCC | Analog Supply Input. | | |
| 8, 29 (Exposed Pad) | AGND | Analog Ground. Connect to the thermal pad. The exposed pad must be soldered to a large PCB and connected to AGND for maximum power dissipation. | | |
| 9 | GVDD | High Side FET Gate Drive Supply. Nominal voltage is 4.6V. | | |
| 10 | PLIMIT | Power Limit Level Adjustment. | | |
| 11 | RINN | Negative Audio Input for Right Channel. Biased at 2V. | | |
| 12 | RINP | Positive Audio Input for Right Channel. Biased at 2V. | | |
| 13, 16, 27 | NC | No Internal Connection. | | |
| 14 | MUTE | Mute Logic Input for Audio Amp (Low = outputs enabled). | | |
| 15 | PVCCR | Power Supply Input for Right Channel H-Bridge. Right channel and left channel power supply inputs are connected internally. | | |
| 17 | BSPR | Bootstrap I/O for Right Channel. Positive high side FET. | | |
| 18 | OUTPR | Class-D H-Bridge Positive Output for Right Channel. | | |
| 19, 24 | PGND | Power Ground for H-Bridges. | | |
| 20 | OUTNR | Class-D H-Bridge Negative Output for Right Channel. | | |
| 21 | BSNR | Bootstrap I/O for Right Channel. Negative high side FET. | | |
| 22 | BSNL | Bootstrap I/O for Left Channel. Negative high side FET. | | |
| 23 | OUTNL | Class-D H-Bridge Negative Output for Left Channel. | | |
| 25 | OUTPL | Class-D H-Bridge Positive Output for Left Channel. | | |
| 26 | BSPL | Bootstrap I/O for Left Channel. Positive high side FET. | | |
| 28 PVCCL Power Supply Input for Left Channel H-Bridge. Right channel a power supply inputs are connected internally. | | Power Supply Input for Left Channel H-Bridge. Right channel and left channel power supply inputs are connected internally. | | |





Function Block Diagram



RT9108NL

Operation

The RT9108NL is a 9W (per channel) efficient Class-D audio power amplifier for driving bridged-tied stereo speakers. The RT9108NL uses the three-level modulation scheme (BD model) that allows operation without the classic LC reconstruction filter when the amplifier drives is driving an inductive load. The internal close-loop modulator enables the negative error feedback, which improves the THD+N of output signal.

An adjustable power limiter is included in the modulator to protect the load speaker. The adjustable power limiter allows the user to set a "virtual" voltage rail lower than the chip supply to limit the amount of current through the speaker. RT9108NL has protection from over current conditions caused by a short circuit on the output stage. The short circuit protection fault is reported on the FAULT pin as a low state. The amplifier outputs are switched to a Hi-Z state when the short circuit protection latch is engaged. The latch can be cleared by cycling the SD pin through the low state. If automatic recovery from the short circuit protection latch is desired, connect the FAULT pin directly to the SD pin. This allows the FAULT pin function to automatically drive the \overline{SD} pin low which clears the short-circuit protection latch.

The RT9108NL can drive stereo speakers as low as 4Ω . The high efficiency of the RT9108NL, 88%, eliminates the need for an external heat sink when playing music.

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Absolute Maximum Ratings (Note 1)

| • | Supply Input Voltage, PVCCL, PVCCR, AVCC | –0.3V to 22V |
|---|--|-------------------------|
| • | Input Voltage, SD, GAIN0, GAIN1, FAULT | -0.3V to (AVCC + 0.3V) |
| • | Output Voltage, OUTPR, OUTPL, OUTNR, OUTNL | -0.3V to (PVCCx + 0.3V) |
| • | Bootstrap Voltage, BSPR, BSPL, BSNR, BSNL | -0.3V to (PVCCx + GVDD) |
| • | Other Pins | -0.3V to (GVDD + 0.3V) |
| • | Power Dissipation, $P_D @ T_A = 25^{\circ}C$ | |
| | TSSOP-28 (Exposed pad) | 3.571W |
| • | Package Thermal Resistance (Note 2) | |
| | TSSOP-28 (Exposed pad), θ_{JA} | 28°C/W |
| | TSSOP-28 (Exposed pad), θ_{JC} | 7°C/W |
| • | Junction Temperature | 150°C |
| • | Lead Temperature (Soldering, 10 sec.) | 260°C |
| • | Storage Temperature Range | –65°C to 150°C |
| • | ESD Susceptibility (Note 3) | |
| | HBM (Human Body Model) | 2kV |
| | MM (Machine Model) | 200V |
| | | |

Recommended Operating Conditions (Note 4)

| • | Supply Input Voltage, PV _{CC} | 8V to 16V |
|---|--|----------------------------------|
| • | Junction Temperature Range | $-40^{\circ}C$ to $125^{\circ}C$ |
| • | Ambient Temperature Range | $-40^{\circ}C$ to $85^{\circ}C$ |

Electrical Characteristics

(PV_{CCx} = 12V, $R_L = 8\Omega$, $T_A = 25^{\circ}C$, unless otherwise specified)

| Parameter | | Symbol | Test Conditions | | Min | Тур | Мах | Unit |
|--|---|-------------------------|---|------------------------------|-----|-----|-----|--|
| SD, GAIN0, Logic-High | | VIH | | | 3 | | | N |
| GAIN1, MUTE Input Voltage | GAIN1, MUTE Input Voltage Logic-Low | | | | | | 0.8 | V |
| Low Level Output | Voltage | V _{OL} | FAULT, $R_{PULL-UP} = 100 k\Omega$ | | | | 0.8 | V |
| High Level Input (| Current | IIH | SD, GAIN0, GAIN1, M | /IUTE, VI = 3V | | | 50 | μA |
| Low Level Input C | urrent | ۱ _{۱L} | SD, GAIN0, GAIN1, M | /IUTE, V _I = 0.8V | | | 10 | μA |
| Class-D Output Offset Voltage (measured differentially) | | Vos | V _I = 0V, Gain = 36dB | | | 5 | 30 | mV |
| Quiescent Supply Current | | lq | $V_{\overline{SD}} = 3V$, no load | | | 20 | 50 | mA |
| Quiescent Supply Shutdown Mode | Quiescent Supply Current in Shutdown Mode | | $V_{\overline{SD}} = 0.8V$, no load | | | 250 | 400 | μA |
| Drain-Source On- | State | Provenu | I _O = 500mA, T _J = | High Side | | 250 | | mΩ |
| Resistance | | R _{DS(ON)} 25° | 25°C | Low Side | | 250 | | 1115.2 |
| Gain | | $V_{GAIN1} = 0.8V$ | \/0 <u>0</u> | $V_{GAIN0} = 0.8V$ | 19 | 20 | 21 | |
| | | | $V_{GAIN0} = 3V$ | 25 | 26 | 27 | dB | |
| | | G | V _{GAIN1} = 3V V _{GAI} | | 31 | 32 | | 33 |
| | | | | | 35 | 36 | 37 | <u>] </u> |

RT9108NL



| Parameter | Symbol | Test Conditions | Min | Тур | Max | Unit |
|--------------------------------------|---------------------|--|-----|------|-----|------|
| PVCC Over Voltage Lockout | PV _{CC_OV} | | | 18 | | V |
| Turn-On Time | t _{ON} | $V_{\overline{SD}} = 3V$ | | 50 | | ms |
| Turn-Off Time | tOFF | $V_{\overline{SD}} = 0.8V$ | | 2 | | ms |
| Gate Drive Supply | V _{GVDD} | $I_{GVDD} = 2mA$ | 4.2 | 4.6 | 5 | V |
| Power Supply Ripple Rejection | PSRR | 200mVPP ripple at 1kHz, Gain = 20dB, Inputs ac-coupled to AGND | | -60 | | dB |
| Continuous Output Power | Po | THD + N = 10%, f_{IN} = 1kHz, PV _{CC} = 13V | | 10 | | W |
| Total Harmonic Distortion + Noise | THD + N | f_{IN} = 1kHz, P _O = 7.5W (half-power), R _L = 8Ω | | 0.15 | | % |
| Output Integrated Noise | V _N | 20Hz to 22kHz, A-weighted filter, | | 120 | | μV |
| | | Gain = 20dB | | -80 | | dBV |
| Crosstalk | | $V_O = 1V_{RMS}$, Gain = 20dB, f _{IN} = 1kHz | | -80 | | dB |
| Signal-to-Noise Ratio | SNR | Maximum output at THD + N < 1%, $f_{IN} = 1$ kHz, Gain = 20dB, A-weighted filter | | 95 | | dB |
| Oscillator Frequency | fosc | | 220 | 300 | 380 | kHz |
| Thermal Trip Point | T _{SD} | | | 150 | | °C |
| Thermal Hysteresis | ΔT_{SD} | | | 15 | | °C |

Note 1. Stresses beyond those listed "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions may affect device reliability.

- Note 3. Devices are ESD sensitive. Handling precaution is recommended.
- Note 4. The device is not guaranteed to function outside its operating conditions.

Note 2. θ_{JA} is measured at $T_A = 25^{\circ}C$ on a low effective thermal conductivity single-layer test board per JEDEC 51-3. θ_{JC} is measured at the exposed pad of the package.

Typical Application Circuit

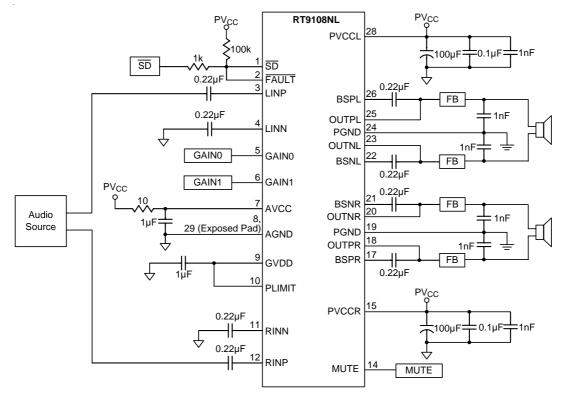
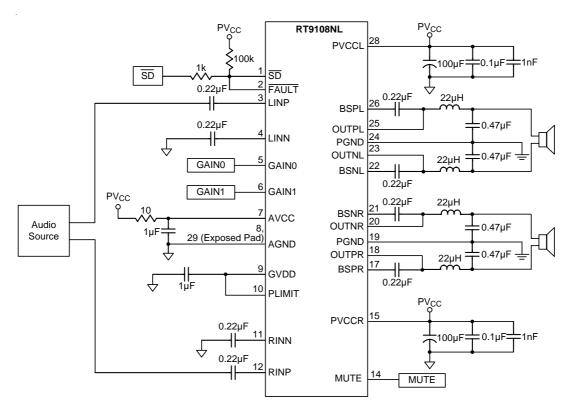


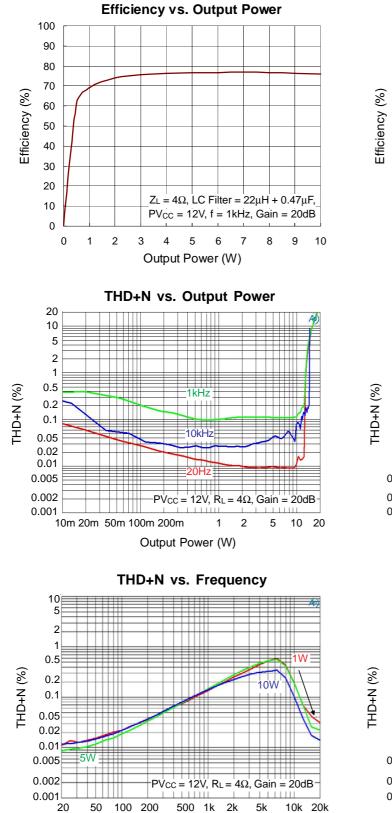
Figure 1. Typical Application Circuit



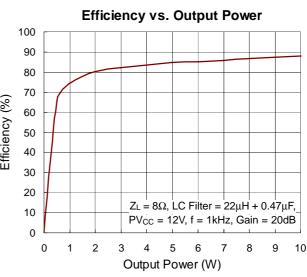




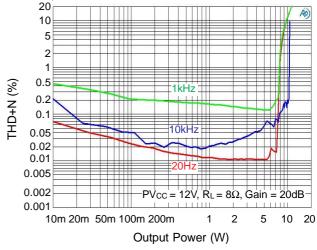
Typical Operating Characteristics

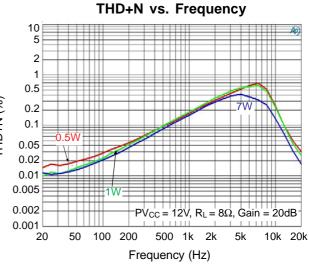


Frequency (Hz)



THD+N vs. Output Power

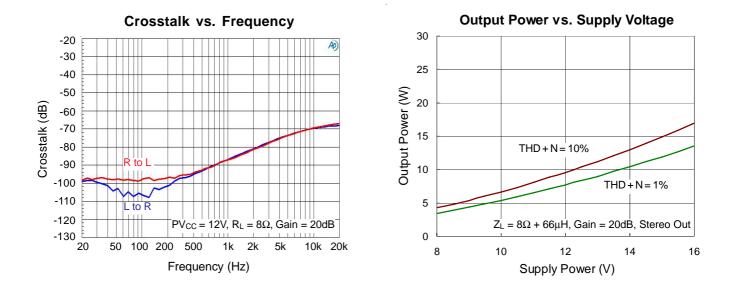




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Application Information

Amplifier Gain Setting

The gain of the RT9108NL amplifier can be set by two input terminals, GAIN0 and GAIN1, shown as Table 1.

The gain setting is realized by changing the taps on the input resistors and feedback resistors inside the amplifier. This causes the input impedance (Z_i) to be dependent on the gain setting. The actual gain settings are controlled by the ratios of the resistors, so the gain variation from part-to-part is small. However, the input impedance from part-to-part at the same gain may shift by ±20% due to shifts in the actual resistance of the input resistor.

| | GAIN0 | Amplifier | Input Impedance | | | | |
|-------|-------|-----------|-----------------|--|--|--|--|
| GAIN1 | | GAIN (dB) | (Ω) | | | | |
| | | Тур | Тур | | | | |
| 0 | 0 | 20 | 100k | | | | |
| 0 | 1 | 26 | 50k | | | | |
| 1 | 0 | 32 | 25k | | | | |
| 1 | 1 | 36 | 12.5k | | | | |

Table 1. Gain Setting

SD Operation

The RT9108NL employs a shutdown mode operation designed to reduce supply current (I_{CC}) to the absolute minimum level for power saring. The \overline{SD} input terminal should be held high (see specification table for trip point) in normal operation. Pulling \overline{SD} low causes the outputs to mute and the amplifier to enter a low current state. Leaving SD floating will cause the, amplifier operation to be unpredictable. Never leave SD pin unconnected!

For the best power off pop performance, tarn off the amplifier in the shutdown mode prior to removing the power supply voltage.

GVDD Supply

The GVDD Supply is used to supply the gate drivers for the output full bridge transistors. Connect a 1μ F capacitor from this pin to ground. The typical GVDD output voltage is 4.6V.

Power LIMIT

The voltage at pin 10 can used to limit the power to levels below the supply rail. Add a resistor divider from GVDD to ground to set the voltage at the PLIMLT pin. An external reference may also be used if tighter tolerance is required. Also add a 1μ F capacitor from pin 10 to ground.

There are five steps to sets a limit on the output peak-topeak voltage. The limiting is done by limiting the duty cycle to fixed maximum value. PLIMIT pin directly connect to GVDD for no power limit.

Output Power = $\frac{PVCC^2}{R_L \times 1.35} \times (Width_Factor)$

Table 2. PLIMIT Width Limit

| PLIMIT Voltage (V) | Width_Factor |
|--------------------|--------------|
| 4.6 (GVDD) | 1 |
| 2.7 to 2.9 | 0.765 |
| 2.3 to 2.5 | 0.578 |
| 1.9 to 2.1 | 0.410 |
| 1.6 to 1.7 | 0.265 |
| 1.2 to 1.3 | 0.149 |

| PVCC = 12V, V _{IN} = 1.5V _{RMS} ,R _L =8Ω | Gain = 20dB | Gain = 26dB | Gain = 32dB | Gain = 36dB |
|--|------------------|------------------|------------------|------------------|
| PLIMIT Voltage (V) | Output Power (W) | Output Power (W) | Output Power (W) | Output Power (W) |
| 4.6 (GVDD) | 11.6 | 13.3 | 14 | 14.3 |
| 2.7 to 2.9 | 9.13 | 10.2 | 10.7 | 10.8 |
| 2.3 to 2.5 | 7.01 | 7.67 | 7.95 | 8.2 |
| 1.9 to 2.1 | 5.07 | 5.36 | 5.47 | 5.6 |
| 1.6 to 1.7 | 3.36 | 3.43 | 3.55 | 3.6 |
| 1.2 to 1.3 | 1.95 | 1.97 | 1.98 | 2 |

 Table 3. Typical PLIMIT Operation at 12V Power Supply

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Short Circuit Protection and Automatic Recovery

The RT9108NL has protection from over current conditions caused by a short circuit on the output stage. The short circuit protection fault is reported on the FAULT pin as a low state. The amplifier outputs are switched to a Hi-Z state when the short circuit protection latch is engaged. The latch can be cleared by cycling the \overline{SD} pin through the low state.

If automatic recovery from the short circuit protection latch is desired, connect the FAULT pin directly to the \overline{SD} pin. This allows the FAULT pin function to automatically drive the \overline{SD} pin low which clears the short-circuit protection latch.

Thermal Protection

Thermal protection on the RT9108NL prevents damage to the device when the internal die temperature exceeds 150° C. There is a $\pm 15^{\circ}$ C tolerance on this trip point from device to device. Once the die temperature exceeds the thermal set point, the device enters shutdown state and the outputs are disabled. This is not a latched fault. The thermal fault is cleared once the temperature of the die is reduced by 15° C. The device begins normal operation at this point with no external system interaction.

Thermal protection faults are NOT reported on the FAULT terminal.

Thermal Considerations

For continuous operation, do not exceed absolute maximum junction temperature. The maximum power dissipation depends on the thermal resistance of the IC package, PCB layout, rate of surrounding airflow, and difference between junction and ambient temperature. The maximum power dissipation can be calculated by the following formula :

 $\mathsf{P}_{\mathsf{D}(\mathsf{MAX})} = (\mathsf{T}_{\mathsf{J}(\mathsf{MAX})} - \mathsf{T}_{\mathsf{A}}) / \theta_{\mathsf{JA}}$

where $T_{J(MAX)}$ is the maximum junction temperature, T_A is the ambient temperature, and θ_{JA} is the junction to ambient thermal resistance.

For recommended operating condition specifications, the maximum junction temperature is 125°C. The junction to ambient thermal resistance, θ_{JA} , is layout dependent. For TSSOP-28 (Exposed Pad) package, the thermal resistance, θ_{JA} , is 28°C/W on a standard JEDEC 51-3 single-layer thermal test board. The maximum power dissipation at T_A =25°C can be calculated by the following formula :

 $P_{D(MAX)} = (125^{\circ}C - 25^{\circ}C) / (28^{\circ}C/W) = 3.571W$ for TSSOP-28 (Exposed Pad) package

The maximum power dissipation depends on the operating ambient temperature for fixed $T_{J (MAX)}$ and thermal resistance, θ_{JA} . The derating curve in Figure 3 allows the designer to see the effect of rising ambient temperature on the maximum power dissipation.

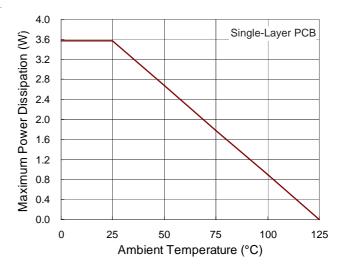


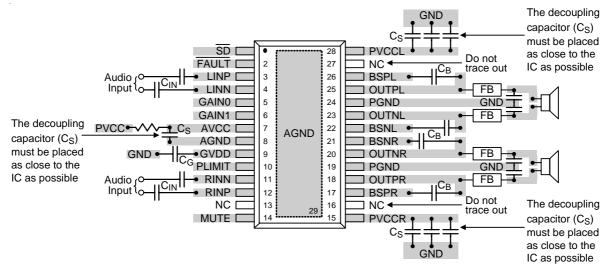
Figure 3. Derating Curve of Maximum Power Dissipation

RT9108NL

Layout Considerations

For the best performance of the RT9108NL, the below PCB Layout guidelines must be strictly followed.

- Place the decoupling capacitors as close as possible to the AVCC, PVCCL, PVCCR and GND pins. For achieving a good quality, consider adding a small, good performance low ESR ceramic capacitor between 220 pF and 1000pF and a larger mid-frequency capacitor between 0.1µF and 1µF to the PVCC pins of the chip. Do not trace out the NC pins (Pin13, 16 and Pin27) to avoid the pin short issue.
- Keep the differential output traces as wide and short as possible.
- The traces of (LINP & LINN, RINP & RINN) and (OUTPL & OUTNL, OUTPR & OUTNR) should be kept equal width and length respectively.
- The thermal pad must be soldered to the PCB for proper thermal performance and optimal reliability. The dimensions of the thermal pad and thermal land should be larger for application. The vias should connect to a solid copper plane, either on an internal layer or on the bottom layer of the PCB.







Outline Dimension

| EXPOSED THERMAL PAD (Bottom of Package) |
|--|
| |

| Symbol | | Dimensions | n Millimeters | Dimensions In Inches | | |
|----------|---|------------|---------------|----------------------|-------|--|
| | | Min | Max | Min | Max | |
| A | | 1.000 | 1.200 | 0.039 | 0.047 | |
| A1 | | 0.000 | 0.150 | 0.000 | 0.006 | |
| A2 | | 0.800 | 1.050 | 0.031 | 0.041 | |
| b | | 0.190 | 0.300 | 0.007 | 0.012 | |
| D | | 9.600 | 9.800 | 0.378 | 0.386 | |
| е | | 0.650 | | 0.026 | | |
| E | | 6.300 | 6.500 | 0.248 | 0.256 | |
| E1 | | 4.300 | 4.500 | 0.169 | 0.177 | |
| L | | 0.450 | 0.750 | 0.018 | 0.030 | |
| Option 1 | U | 4.410 | 5.510 | 0.174 | 0.217 | |
| Option 1 | V | 2.400 | 3.000 | 0.094 | 0.118 | |
| Ontion 0 | U | 5.500 | 6.170 | 0.217 | 0.243 | |
| Option 2 | V | 1.600 | 2.210 | 0.063 | 0.087 | |
| Option 3 | U | 5.800 | 6.200 | 0.228 | 0.244 | |
| | V | 2.600 | 3.000 | 0.102 | 0.118 | |

28-Lead TSSOP (Exposed Pad) Plastic Package

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